

**Diode, Wechselrichter / Diode, Inverter**  
**Höchstzulässige Werte / Maximum Rated Values**

|   |  |           |            |  |
|---|--|-----------|------------|--|
| Periodische Spitzensperrspannung<br>Repetitive peak reverse voltage | $T_{vj} = 25^{\circ}\text{C}$  | $V_{RRM}$ | 1200       | V  |
| Dauergleichstrom<br>Continuous DC forward current                   |  | $I_F$     | 50         | A  |
| Periodischer Spitzenstrom<br>Repetitive peak forward current        | $t_P = 1\text{ ms}$  | $I_{FRM}$ | 100        | A  |
| Grenzlastintegral<br>$I^2t$ - value                                 | $V_R = 0\text{ V}, t_P = 10\text{ ms}, T_{vj} = 125^{\circ}\text{C}$<br>$V_R = 0\text{ V}, t_P = 10\text{ ms}, T_{vj} = 175^{\circ}\text{C}$ | $I^2t$    | 300<br>250 | $\text{A}^2\text{s}$<br>$\text{A}^2\text{s}$ |

**Charakteristische Werte / Characteristic Values**

|  |   |   | min.               | typ.                 | max.   |   |
|--|---|---|--------------------|----------------------|--------|---|
| Durchlassspannung<br>Forward voltage   | $I_F = 50\text{ A}, V_{GE} = 0\text{ V}$<br>$I_F = 50\text{ A}, V_{GE} = 0\text{ V}$<br>$I_F = 50\text{ A}, V_{GE} = 0\text{ V}$          | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 175^{\circ}\text{C}$ | $V_F$              | 1,72<br>1,59<br>1,52 | t.b.d. | V<br>V<br>V                                     |
| Rückstromspitze<br>Peak reverse recovery current                                 | $I_F = 50\text{ A}, -di_F/dt = 1650\text{ A}/\mu\text{s} (T_{vj}=175^{\circ}\text{C})$<br>$V_R = 600\text{ V}$<br>$V_{GE} = -15\text{ V}$ | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 175^{\circ}\text{C}$ | $I_{RM}$           | 42,5<br>53,0<br>60,5 |        | A<br>A<br>A                                     |
| Sperrverzögerungsladung<br>Recovered charge                                      | $I_F = 50\text{ A}, -di_F/dt = 1650\text{ A}/\mu\text{s} (T_{vj}=175^{\circ}\text{C})$<br>$V_R = 600\text{ V}$<br>$V_{GE} = -15\text{ V}$ | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 175^{\circ}\text{C}$ | $Q_r$              | 3,74<br>8,19<br>10,4 |        | $\mu\text{C}$<br>$\mu\text{C}$<br>$\mu\text{C}$ |
| Abschaltenergie pro Puls<br>Reverse recovery energy                              | $I_F = 50\text{ A}, -di_F/dt = 1650\text{ A}/\mu\text{s} (T_{vj}=175^{\circ}\text{C})$<br>$V_R = 600\text{ V}$<br>$V_{GE} = -15\text{ V}$ | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 175^{\circ}\text{C}$ | $E_{rec}$          | 1,72<br>3,06<br>3,73 |        | mJ<br>mJ<br>mJ                                  |
| Wärmewiderstand, Chip bis Kühlkörper<br>Thermal resistance, junction to heatsink | pro Diode / per diode   |   | $R_{thJH}$         | 1,22                 |        | K/W   |
| Temperatur im Schaltbetrieb<br>Temperature under switching conditions            |   |   | $T_{vj\text{ op}}$ | -40                  | 175    | $^{\circ}\text{C}$                              |

**NTC-Widerstand / NTC-Thermistor**

**Charakteristische Werte / Characteristic Values**

|  |   |  | min.         | typ. | max. |            |
|--|---|--|--------------|------|------|------------|
| Nennwiderstand<br>Rated resistance       | $T_{NTC} = 25^{\circ}\text{C}$                                |  | $R_{25}$     | 5,00 |      | k $\Omega$ |
| Abweichung von R100<br>Deviation of R100 | $T_{NTC} = 100^{\circ}\text{C}, R_{100} = 493\ \Omega$        |  | $\Delta R/R$ | -5   | 5    | %          |
| Verlustleistung<br>Power dissipation     | $T_{NTC} = 25^{\circ}\text{C}$                                |  | $P_{25}$     |      | 20,0 | mW         |
| B-Wert<br>B-value                        | $R_2 = R_{25} \exp [B_{25/50}(1/T_2 - 1/(298,15\text{ K}))]$  |  | $B_{25/50}$  | 3375 |      | K          |
| B-Wert<br>B-value                        | $R_2 = R_{25} \exp [B_{25/80}(1/T_2 - 1/(298,15\text{ K}))]$  |  | $B_{25/80}$  | 3411 |      | K          |
| B-Wert<br>B-value                        | $R_2 = R_{25} \exp [B_{25/100}(1/T_2 - 1/(298,15\text{ K}))]$ |  | $B_{25/100}$ | 3433 |      | K          |

Angaben gemäß gültiger Application Note.  
Specification according to the valid application note.

## Vorläufige Daten Preliminary Data

### Modul / Module

|   |   |                      |                                |      |      |    |
|---|---|----------------------|--------------------------------|------|------|----|
| Isolations-Prüfspannung<br>Isolation test voltage   | RMS, f = 50 Hz, t = 1 min.  | V <sub>ISOL</sub>    | 2,5                            |      |      | kV |
| Innere Isolation<br>Internal isolation  | Basisisolierung (Schutzklasse 1, EN61140)<br>basic insulation (class 1, IEC 61140)      |                      | Al <sub>2</sub> O <sub>3</sub> |      |      |    |
| Kriechstrecke<br>Creepage distance  | Kontakt - Kühlkörper / terminal to heatsink<br>Kontakt - Kontakt / terminal to terminal |                      | 11,5<br>6,3                    |      |      | mm |
| Luftstrecke<br>Clearance  | Kontakt - Kühlkörper / terminal to heatsink<br>Kontakt - Kontakt / terminal to terminal |                      | 10,0<br>5,0                    |      |      | mm |
| Vergleichszahl der Kriechwegbildung<br>Comperative tracking index                         |   | CTI                  | > 200                          |      |      |    |
| Relativer Temperaturindex (elektr.)<br>RTI Elec.  | Gehäuse<br>housing  | RTI                  | 140                            |      |      | °C |
|   |   |                      | min.                           | typ. | max. |    |
| Modulstreuinduktivität<br>Stray inductance module   |   | L <sub>sCE</sub>     |                                | 40   |      | nH |
| Modulleitungswiderstand, Anschlüsse -<br>Chip<br>Module lead resistance, terminals - chip | T <sub>H</sub> = 25°C, pro Schalter / per switch  | R <sub>CC'+EE'</sub> |                                | 4,00 |      | mΩ |
| Lagertemperatur<br>Storage temperature  |   | T <sub>stg</sub>     | -40                            |      | 125  | °C |
| Anpresskraft für mech. Bef. pro Feder<br>mounting force per clamp                         |   | F                    | 40                             | -    | 80   | N  |
| Gewicht<br>Weight   |   | G                    |                                | 39   |      | g  |

Der Strom im Dauerbetrieb ist auf 25 A effektiv pro Anschlusspin begrenzt.

The current under continuous operation is limited to 25 A rms per connector pin.

T<sub>vj op</sub> > 150°C ist im Überlastbetrieb zulässig. Detaillierte Angaben sind AN 2018-14 zu entnehmen.

T<sub>vj op</sub> > 150°C is allowed for operation at overload conditions. For detailed specifications, please refer to AN 2018-14.